

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	125	spin adj transistor and @pd > "19970805"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/14 10:05
L2	4	"6355953"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/14 10:23
L3	90	(ferromagnet ferromagnetic ferromagnetically) and (1 2)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/14 10:23
L4	3	((("5465185") or ("5654566") or ("5962905"))).PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/14 10:42
S75	5	TEHRANI and ferromagnetic and (sputtering sputter sputtered) and (epitaxial epitaxially) and (source drain)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/13 16:44
S76	3	("20040041217" "20040178460"). PN. and (manganese GaMn Mn GaMnAs InMnAs GeMn GaMnN line adj width half adj metal)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/13 16:44
S77	0	spintronic and (two adj dimension two adj dimensional two-dimension two-dimensional) adj gas	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 16:47
S78	0	(spin-valve spintronic) and (two adj dimension two adj dimensional two-dimension two-dimensional) adj gas	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 16:49
S79	255	(two adj dimension two adj dimensional two-dimension two-dimensional) adj gas	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 16:48
S80	1459	(spin-valve spintronic)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 16:49

S81	7	(spin-valve spintronic) and SOI	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 16:57
S82	1271	(spin-valve spintronic) and (chromate chromium oxide Fe Co FeCo Ni FeNi NiFe Co Fe)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 16:59
S83	17	S82 and (Mn near3 (GaAs InAs) GaMnAs InMnAs)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 17:03
S84	1275	(spin-valve spintronic) and (chromate chromium oxide Fe Co FeCo Ni FeNi NiFe CoFe Mn near3 (GaAs InAs) GaMnAs InMnAs)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 17:05
S85	553	(spin-valve spintronic) and (Fe Co FeCo Ni FeNi NiFe CoFe) and (Si Ge SiGe GaAs InAs InGaAs GaInAs)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 17:35
S87	13	(spin-valve spintronic) and (chromate chromium adj oxide) and (Si Ge SiGe GaAs InAs InGaAs GaInAs)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 18:14
S88	1	("6613448").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/13 17:20
S89	1	(spin-valve spintronic) and (chromium adj dioxide) and (Si Ge SiGe GaAs InAs InGaAs GaInAs) not S87	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 17:27
S90	11	"6285581"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 17:27
S91	199	TEHRANI and mram	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/13 17:28

S92	19	TEHRANI and spin-valve	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/13 17:28
S93	201	S91 or S92	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/13 17:28
S94	11	spin-injection and (Fe Co FeCo Ni FeNi NiFe CoFe) and (Si Ge SiGe GaAs InAs InGaAs GaInAs)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/02/13 17:30
S95	14	(spintronic and ferromagnetic and semiconductor) and schottky	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 17:31
S97	4	(spintronic and ferromagnetic and semiconductor) and schottky and (doping dopant doped)	US-PGPUB; USPAT	OR	OFF	2005/02/13 17:31
S98	14	((spintronic and ferromagnetic and semiconductor) and schottky and (doping dopant doped))	US-PGPUB; USPAT	OR	ON	2005/02/13 17:32
S10 0	1566	((257/75,295,421) or (324/249) or (360/324.1) or (365/158,171,175) or (438/3)).CCLS. and @pd>"20030917"	US-PGPUB; USPAT	OR	OFF	2005/02/13 17:33
S10 1	72	(spin-valve spintronic) and (Fe Co FeCo Ni FeNi NiFe CoFe) and (Si Ge SiGe GaAs InAs InGaAs GaInAs) and (injection injecting injector injected)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 18:01
S10 2	0	"20020268055"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 18:02
S10 3	4	"6355953"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 18:02
S10 4	3	"6355953"	US-PGPUB; USPAT	OR	ON	2005/02/13 18:07
S10 6	10	"6285581"	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	ON	2005/02/13 18:07

S10 7	0	spin-transistor and (chromate chromium adj oxide) and (Si Ge SiGe GaAs InAs InGaAs GaInAs)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 18:14
S10 8	0	spin adj transistor and (chromate chromium adj oxide) and (Si Ge SiGe GaAs InAs InGaAs GaInAs)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 18:14
S10 9	139	spin adj transistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/13 18:21